AMENDMENTS TO THE SPECIFICATION

Please rewrite the paragraph at page 1, lines 2-4, to read as follows:

-- BACKGROUND OF THE INVENTION

The invention relates to a semiconductor structure, particularly for use in a semiconductor detector, according to the <u>invention</u>preamble of Claim 1. --

Please rewrite the paragraph on page 3, lines 3-5, to read as follows:

-- SUMMARY OF THE INVENTION

This task, proceeding on the basis of the known DEPFET structure as described above according to the preamble of Claim 1, is solved by the designating features of Claim 1.--

Please add on page 10, between lines 26 and 27, the following heading:

-- BRIEF DESCRIPTION OF SEVERAL VIEWS OF THE DRAWINGS --

Please add on page 13, between lines 3 and 4, the following heading:

-- DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENTS --